Quasi-3D Modeling of Electron Cyclotron Resonance Ion Source (ECRIS) Plasmas*

Presented by Jin-Soo Kim
Work performed by E.G. Evstatiev, C.C. Kim, L. Zhao and J.S. Kim

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FAR-TECH, Inc. Management and Facility

• Located in San Diego, CA

• Founded in 1994, formerly known as Fusion and Accelerator Research (FAR), to pursue fusion and accelerator related research, technology and development.

• Core staff of 16 (14 PhDs)

• Facility:
  – Linux cluster (88 processors) with 96GB of memory via Infiniband connection; 15 TB redundant storage
  – RF laboratory
Highly charged ions are needed for Nuclear Physics studies, medical and industrial applications.

Primary means for high charge (rare) ions are Electron Cyclotron Resonance Ion Sources (ECRIS) / Electron Cyclotron Resonance Charge Breeders (ECRCB).

Modeling of ECRIS/ECRCB plasmas is needed to guide, interpret and optimize current experiments and to design expensive next generation devices.
Develop a (Quasi3D) numerical tool for optimizing the design and operation of an ECRIS/ECRCB.

- Simulation should be performed within reasonable time

- Model should be justifiable and capture important physics

- Data-Visualization to be used to help comprehension
Brief description of ECRIS/ECRCB:

They use plasmas confined in a magnetic mirror device for ions to become multiply charged by impact ionization with ECR heated electrons. The longer the ions are confined, the higher the charge states are. Plasma confinement is by magnetic mirrors (axially) and hexapole fields (radially).
Schematics of ECRIS/ECRCB
Many Challenging Questions to be answered

How to maximize extracted highly charged ion current?
- Scaling of extracted current wrt RF frequency
- Sensitivity wrt RF frequency
- Multiple frequency heating
- Volume heating effect

3D profile of extracted ion beams
- charge density
- current density

Minimize extracted ion beam emittance

Parameter study/control knobs for optimization
FAR-TECH’s ECRIS/ECRCB Modeling Status:
Have developed a few modules, each representing distinctive physical process.

1+ ion beam  ECR Plasma  n+ ion beam

MCBC
Monte Carlo Beam Code
Full 3d3v

GEM
Generalized ECRIS Modeling
Fluid
1d2v
2d2v

IonEx/PBGUNS
Ion/beam extraction
2d3v
3D effect of plasma is needed

“Modeling consideration”
FAR-TECH’s two stage plan for 3D simulations

• Emphasis on 3D aspect of Plasma (while using a simple ECRH model)

• Emphasis on realistic modeling of ECRH by through study of rf coupling to plasma (a separate project)

• Combine the two to perform a comprehensive realistic simulation of ECRIS/ECRCB plasmas.
An Electron Orbit in ECRIS/ECRCB

Thin red and blue lines: B-field
Green surface: ECR resonance

Thick purple lines: an electron orbit
Rf amplitude = 0
Drift-kinetic model for electrons

Treat electrons by guiding center motion

Change coordinates:

\[
\begin{pmatrix}
  x \\
  y \\
  z \\
  v_x \\
  v_y \\
  v_z \\
\end{pmatrix} \rightarrow \begin{pmatrix}
  x_g \\
  y_g \\
  z_g \\
  v_{\parallel} \\
  \mu \\
  \Theta \\
\end{pmatrix}
\]

\[\mu = \frac{m v_{\parallel}^2}{2B}; \quad \Theta \text{ is a fast oscillating phase.}\]

Compared to fully kinetic, computational speedup is \(~100.\)
When an electron crosses a resonance surface, it obtains an increase of the perpendicular velocity, with $\Delta v_\perp = \frac{q}{m} E t_e$

$$t_e \approx 1.13 \omega_{rf}^{-1} \left( \frac{2\omega_{rf}}{|\alpha v_{||}|} \right)^{1/2}$$, when turning point is away from the resonant surface

$$t_e \approx 0.71 \omega_{rf}^{-1} \left( \frac{2\omega_{rf}}{|\alpha v_\perp|} \right)^{2/3}$$, when turning point is near the resonant surface

where $\alpha = B_z^{-1}/(dB_z/dz)$ and $E$ is the electric field magnitude.
Numerical simulation of single electron heating

Single particle heating

Time, $\mu$s
ECRIS/ECRCB plasmas modeled by the **SIMPL (SIMulation of PLasmas) code**

- Electrons have guiding center motions with the Lieberman & Lichtenberg ‘kick’ RF-heating model.

- Ions are fully kinetic.

- Atomic collisions included.

Next we show SIMPL simulation results showing a trend of quasi-neutrality and ambipolarity of the plasma.
Ambipolarity (at 20 μs)
Quasi-neutrality (at 20 µs)
CPU estimation

- Currently drift-kinetic calculation takes 2-3 weeks for a 2D ECRIS/ECRCB simulation to ~ ms with ~48 processors.
- Recently obtained an improved algorithm - this allows x10 speedup.
- We believe a 3D ECRIS/ECRCB simulation, to ~ ms evolution, may be achieved in 2 ~ 3 weeks with 48 processors.
Visualization of ECRIS electron orbits and fields

B and E field in ECRIS w/particles

Charlson C. Kim
FAR-TECH, Inc.
Project Status

A drift-kinetic 3D ECRIS/ECRCB modeling code (SIMPL) is being developed:
Electrons are modeled by center motion with a ‘kick’ rf-heating model
Ions are treated fully kinetically.
Basic features are successfully tested.

More realistic modeling of RF-heating is on-going under a separate project

Future work:
- Will implement more complete and realistic atomic and collision model
- Improve computational efficiency by further MPI parallelization and domain decomposition
- Validate code with experiments for charge breeding efficiency, emittance of extracted beams, and charge states.
- Develop user-friendly GUI
- Visualize data for enhanced comprehension
- Support ECRIS/ECRCB facilities
Commercialization

**X-ray Ross Filter sets are installed (at KSTAR)**

**PBGUNS** (particle source code)  
**Pre-buncher to Industry**  
(Custom order)